N-Channel MOS FET SKP202



March. 2007

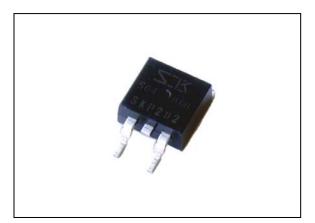
Features

- •Low on-resistance
- •Low input capacitance
- •Avalanche energy capability guaranteed

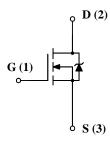
Applications

- PDP driving
- •High speed switching

■Package---TO-263



■Equivalent circuit



■Absolute maximum ratings

	-	T)	a=25°C)
Parameter	Symbol	Rating	Unit
Drain to Source Voltage	VDSS	200	V
Gate to Source Voltage	VGSS	±30	V
Continuous Drain Current	ID	±45A	А
Pulsed Drain Current	ID(pulse) * ¹	±180A	А
Maximum Power Dissipation	PD	95 (Tc=25°C)	W
Single Pulse Avalanche Energy	EAS * ²	200	mJ
Avalanche Current	IAS	45	А
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to 150	°C

*1 PW \leq 100 μ s, duty cycle \leq 1%

*2 VDD=20V, L=180µH, ILp=45A, unclamped, RG=50Ω, See Fig.1



		lectrical characteristics	,		(Ta=25°	C)
Parameter	Symbol	Test Conditions	Limits			
			MIN.	TYP.	MAX.	- Unit
Drain to Source breakdown Voltage	V(BR)DSS	ID=100µA,VGS=0V	200			V
Gate to Source Leakage Current	IGSS	VGS=±30V			±100	nA
Drain to Source Leakage Current	IDSS	VDS=200V, VGS=0V			100	μΑ
Gate Threshold Voltage	VTH	VDS=10V, ID=1mA	3.0		4.5	V
Forward Transconductance	Re(Yfs)	VDS=10V, ID=22A	18	28		S
Static Drain to Source On-Resistance	RDS(on)	ID=22A, VGS=10V		45	53	mΩ
Input Capacitance	Ciss	VDS=25V VGS=0V f=1MHz		2000		pF
Output Capacitance	Coss			400		
Reverse Transfer Capacitance	Crss			80		
Turn-On Delay Time	td(on)	- ID22A, VDD≈100V RL=4.5Ω, VGS=10V RG=5Ω See Fig.2		30		ns
Rise Time	tr			100		
Turn-Off Delay Time	td(off)			90		
Fall Time	tf			50		
Source-Drain Diode Forward Voltage	VSD	ISD=45A,VGS=0V		1.0	1.5	V
Gate Threshold Voltage Temp. Coefficient	ΔVTH /ΔTch	VDS=10V, ID=1mA		-8		mV/°C

Electrical characteristics

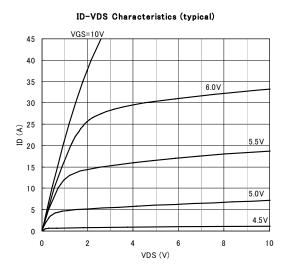
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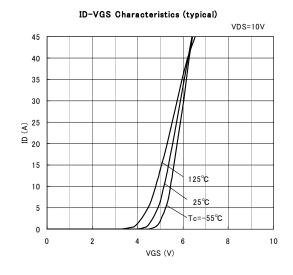
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SanKen

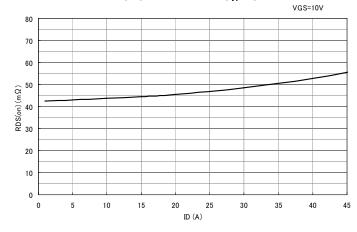
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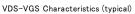
Characteristic Curves (Tc=25°C)

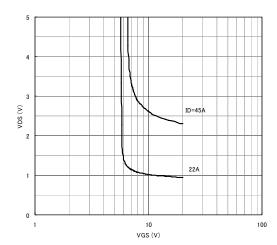


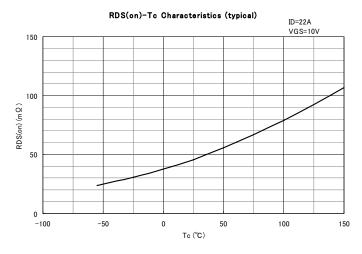


RDS(ON)-ID Characteristics (typical)









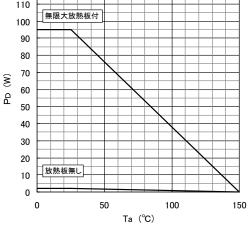
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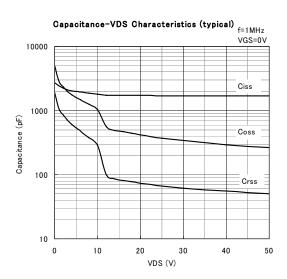
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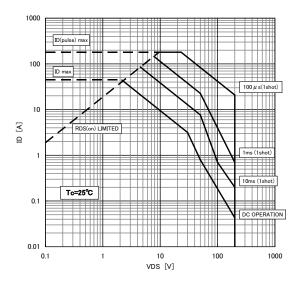


Re(yfs)-ID Characteristics (typical) VDS=10V 100 10 Tc=-55°C Re(yfs) (S) 25°C 1 125°C 0.1 0.01 0.01 0.1 100 10 1 ID (A) IDR-VSD Characteristics (typical) 45 40 35 30 € ²⁵ 법 입 20 100 15 10 VGS=0\ 5 0 0.0 1.5 0.5 1.0 VSD (V) PD — Ta 120 110 無限大放熱板付





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Fig.1 Unclamped Inductive Test Method

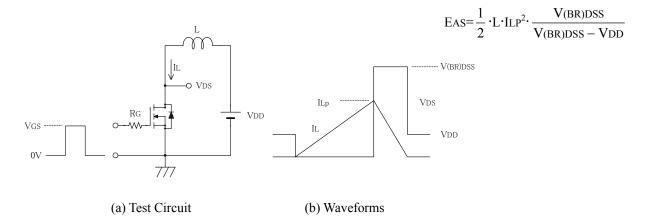
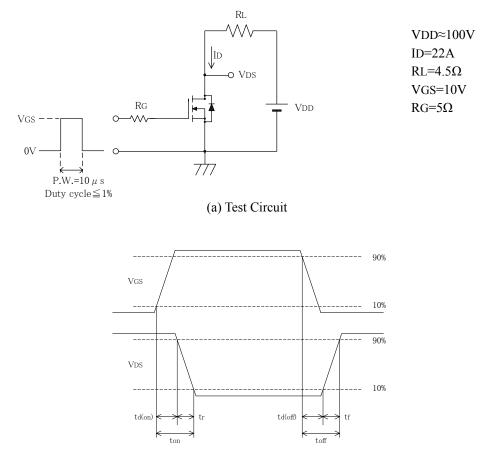


Fig.2 Switching Time Test Method

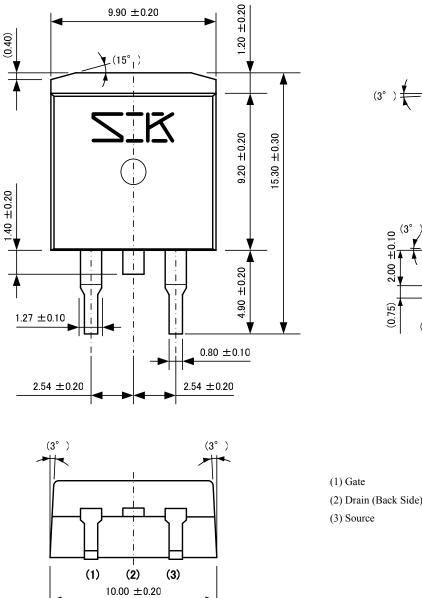


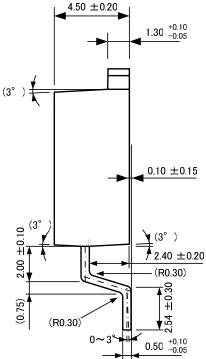
(b) Waveforms



External dimensions

TO-263





Weight Approx. 1.5g

(2) Drain (Back Side)



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March. 2007

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